



IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re the Application of:

Theodore W. Houston

Serial No: 10/635,185

Filed: 08/06/03

For: Asymmetric Static Random Access Memory Device Having Reduced Bit Line Leakage

TI-35149

Art Unit: TBD

Examiner: TBD

INFORMATION DISCLOSURE STATEMENT

Commissioner for Patents

P.O. Box 1450

Alexandria, VA 22313-1450

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Karen Vertz 11-14-03
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Applicants wish to bring to the attention of the Patent and Trademark Office the information noted on the enclosed PTO-1449. A copy of the noted reference is enclosed herewith.

Respectfully submitted,

Rose Alyssa Keagy
Attorney for Applicant
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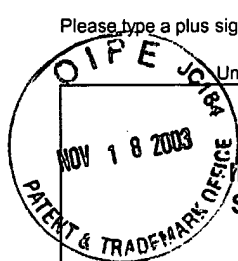
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PTO/SB/08A (08-00)

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INFORMATION DISCLOSURE STATEMENT BY APPLICANT

(use as many sheets as necessary)

Complete If Known

Application Number	10/635,185
Filing Date	08/06/03
First Named Inventor	Theodore W. Houston
Group Art Unit	TBD
Examiner Name	TBD
Attorney Docket No.	TI-35149

Sheet	1	of	1
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U.S. PATENT DOCUMENTS

Exam. Initials*	Cite No. ¹	U.S. Patent Document		Name of Patentee or Applicant of Cited Doc.	Date of Pub. of Cited Doc. (mm-dd-yyyy)	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear
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OTHER PRIOR ART - NON PATENT LITERATURE DOCUMENTS

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	CA	NAVID AZIZI ET AL., "Low-Leakage Asymmetric-Cell SRAM" ISLPED '02, August 12-14, 2002, Monterey, California, USA	
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